

# QM20TG-9B

MEDIUM POWER SWITCHING USE  
INSULATED TYPE

QM20TG-9B



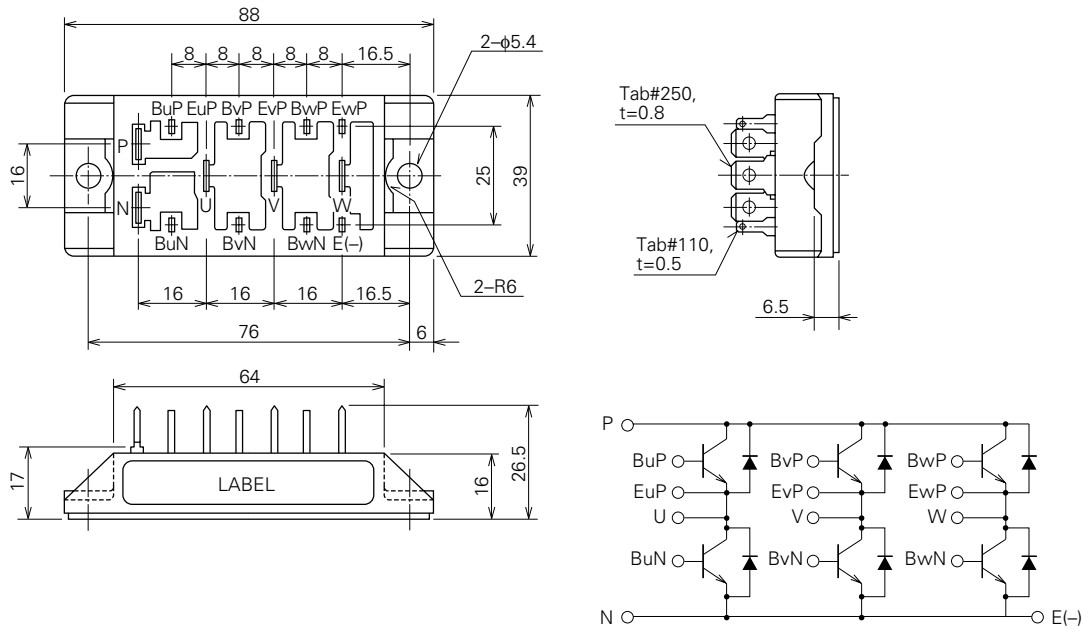
- **I<sub>C</sub>** Collector current ..... **20A**
- **V<sub>CEX</sub>** Collector-emitter voltage ..... **500V**
- **h<sub>FE</sub>** DC current gain ..... **250**
- **Insulated Type**

## APPLICATION

Air conditioner, Small to medium size inverters

## OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



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**ABSOLUTE MAXIMUM RATINGS** (T<sub>j</sub>=25°C, unless otherwise noted)

Symbol	Parameter	Conditions	Ratings	Unit
V <sub>CEX (SUS)</sub>	Collector-emitter voltage	I <sub>c</sub> =1A, V <sub>EB</sub> =2V	450	V
V <sub>CEX</sub>	Collector-emitter voltage	V <sub>EB</sub> =2V	500	V
V <sub>CBO</sub>	Collector-base voltage	Emitter open	500	V
V <sub>EBO</sub>	Emitter-base voltage	Collector open	7	V
I <sub>c</sub>	Collector current	DC	20	A
-I <sub>c</sub>	Collector reverse current	DC (forward diode current)	20	A
P <sub>c</sub>	Collector dissipation	T <sub>c</sub> =25°C	100	W
I <sub>B</sub>	Base current	DC	1	A
-I <sub>CSM</sub>	Surge collector reverse current (forward diode current)	Peak value of one cycle of 60Hz (half wave)	200	A
T <sub>j</sub>	Junction temperature		-40~+150	°C
T <sub>stg</sub>	Storage temperature		-40~+125	°C
V <sub>iso</sub>	Isolation voltage	Charged part to case, AC for 1 minute	2000	V
—	Mounting torque	Mounting screw M5	1.47~1.96	N·m
			15~20	kg·cm
—	Weight	Typical value	70	g

**ELECTRICAL CHARACTERISTICS** (T<sub>j</sub>=25°C, unless otherwise noted)

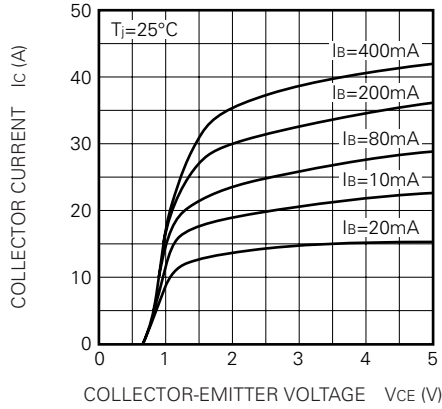
Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
I <sub>CEX</sub>	Collector cutoff current	V <sub>CE</sub> =500V, V <sub>EB</sub> =2V	—	—	1.0	mA
I <sub>CBO</sub>	Collector cutoff current	V <sub>CB</sub> =500V, Emitter open	—	—	1.0	mA
I <sub>EBO</sub>	Emitter cutoff current	V <sub>EB</sub> =7V	—	—	40	mA
V <sub>CE (sat)</sub>	Collector-emitter saturation voltage	I <sub>c</sub> =20A, I <sub>B</sub> =80mA	—	—	2.0	V
V <sub>BE (sat)</sub>	Base-emitter saturation voltage		—	—	2.5	V
-V <sub>CEO</sub>	Collector-emitter reverse voltage	-I <sub>c</sub> =20A (diode forward voltage)	—	—	1.5	V
h <sub>FE</sub>	DC current gain	I <sub>c</sub> =20A, V <sub>CE</sub> =2V	250	—	—	—
t <sub>on</sub>	Switching time	V <sub>CC</sub> =250V, I <sub>c</sub> =20A, I <sub>B1</sub> =120mA, -I <sub>B2</sub> =0.4A	—	—	2.0	μs
t <sub>s</sub>			—	—	10	μs
t <sub>f</sub>			—	—	2.0	μs
R <sub>th (j-c) Q</sub>			Thermal resistance (junction to case)	Transistor part (per 1/6 module)	—	—
R <sub>th (j-c) R</sub>		Diode part (per 1/6 module)	—	—	2.5	°C/W
R <sub>th (c-f)</sub>	Contact thermal resistance (case to fin)	Conductive grease applied (per 1/6 module)	—	—	0.55	°C/W

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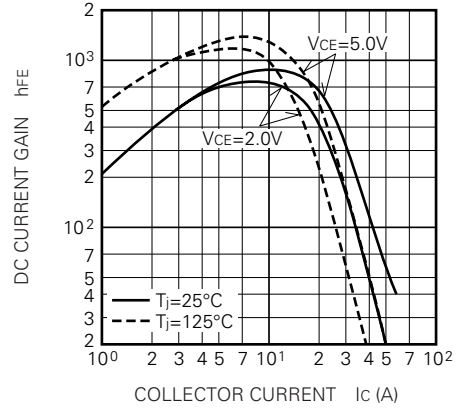
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**PERFORMANCE CURVES**

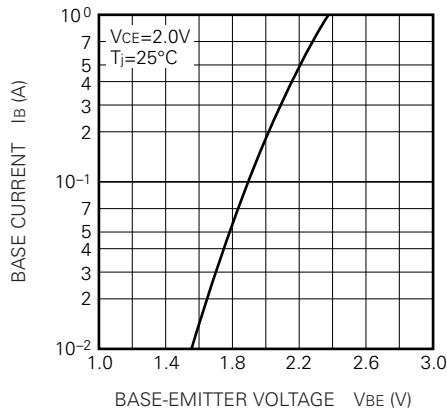
**COMMON EMITTER OUTPUT CHARACTERISTICS (TYPICAL)**



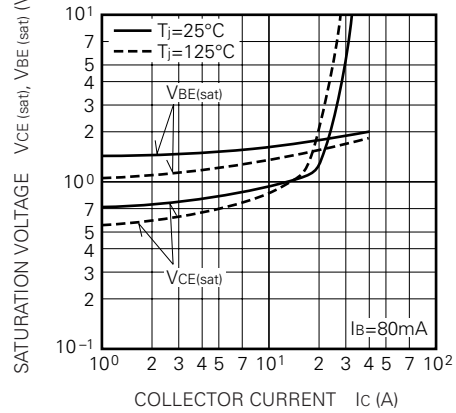
**DC CURRENT GAIN VS. COLLECTOR CURRENT (TYPICAL)**



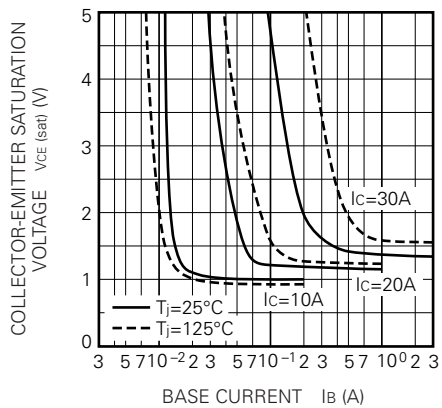
**COMMON EMITTER INPUT CHARACTERISTIC (TYPICAL)**



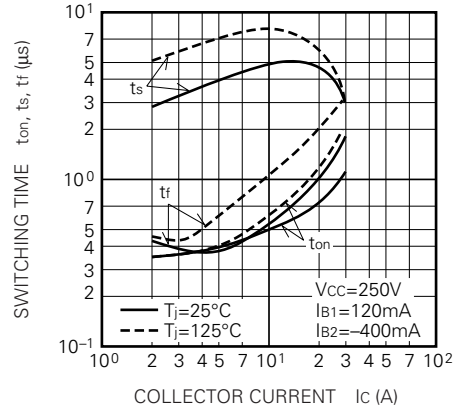
**SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)**



**COLLECTOR-EMITTER SATURATION VOLTAGE (TYPICAL)**



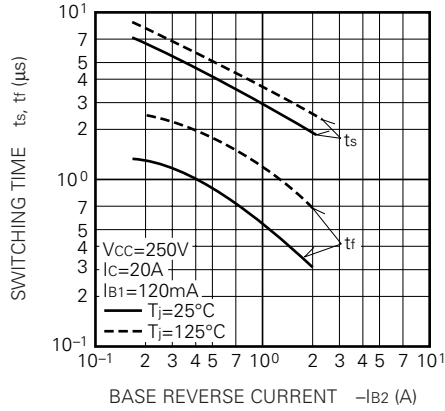
**SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL)**



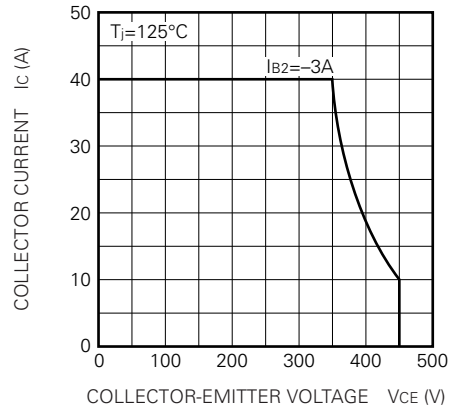
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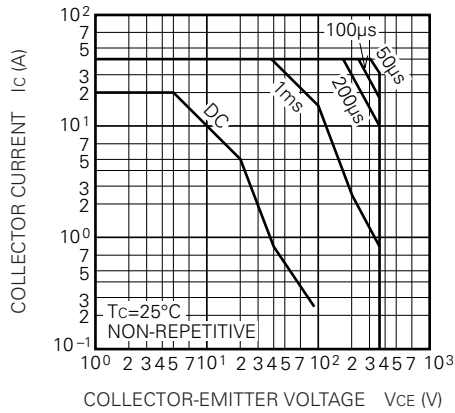
**SWITCHING TIME VS. BASE CURRENT (TYPICAL)**



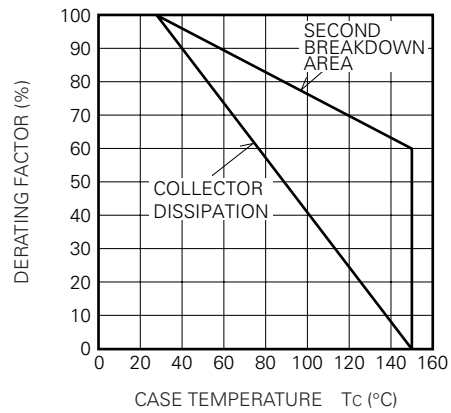
**REVERSE BIAS SAFE OPERATING AREA**



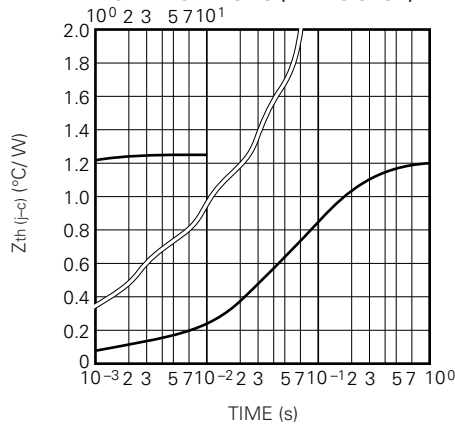
**FORWARD BIAS SAFE OPERATING AREA**



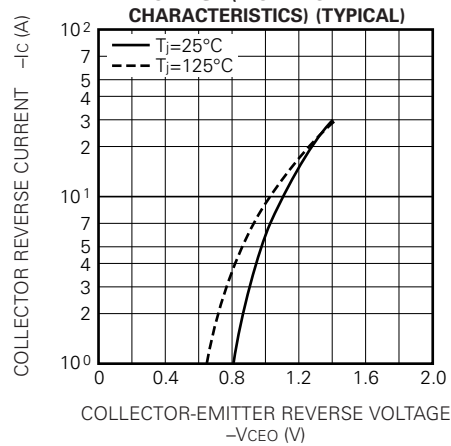
**DERATING FACTOR OF F. B. S. O. A.**



**TRANSIENT THERMAL IMPEDANCE CHARACTERISTIC (TRANSISTOR)**



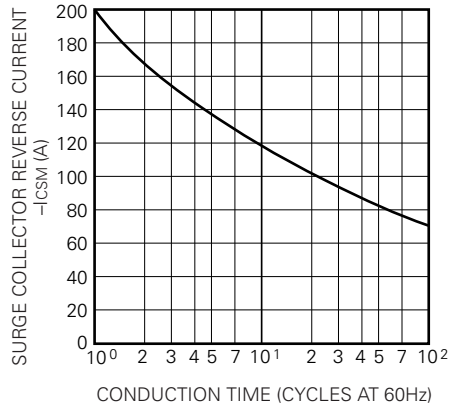
**REVERSE COLLECTOR CURRENT VS. COLLECTOR-EMITTER REVERSE VOLTAGE (DIODE FORWARD CHARACTERISTICS) (TYPICAL)**



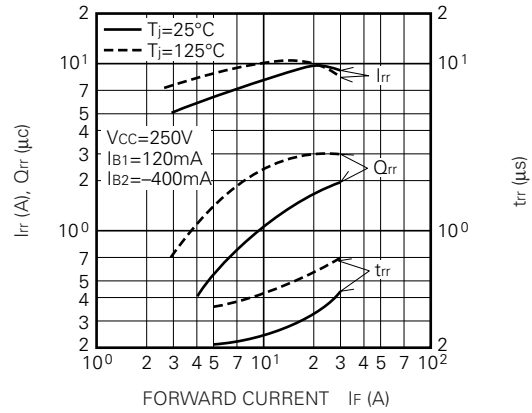
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**RATED SURGE COLLECTOR REVERSE CURRENT  
(DIODE FORWARD SURGE CURRENT)**



**REVERSE RECOVERY CHARACTERISTICS  
OF FREE-WHEEL DIODE (TYPICAL)**



**TRANSIENT THERMAL IMPEDANCE  
CHARACTERISTIC (DIODE)**

